



ON Semiconductor®

www.onsemi.com

MCH3475

Power MOSFET 30V, 180mΩ, 1.8A, Single N-Channel

Features

- High Speed Switching
- 4V Drive
- Pb-Free and RoHS Compliance
- Halogen Free Compliance : MCH3475-TL-W

V _{DSS}	R _{DS(on)} Max	I _D Max
30V	180mΩ@ 10V	1.8A
	330mΩ@ 4V	

Specifications

Absolute Maximum Ratings at T_a = 25°C

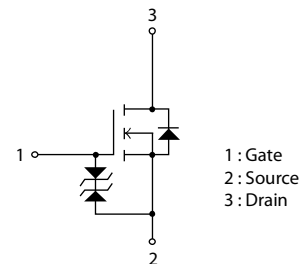
Parameter	Symbol	Value	Unit
Drain to Source Voltage	V _{DSS}	30	V
Gate to Source Voltage	V _{GS}	±20	V
Drain Current (DC)	I _D	1.8	A
Drain Current (Pulse) PW≤10μs, duty cycle≤1%	I _{DP}	7.2	A
Power Dissipation When mounted on ceramic substrate (900mm ² × 0.8mm)	P _D	0.8	W
Junction Temperature	T _J	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

This product is designed to "ESD immunity < 200V*", so please take care when handling.
* Machine Model

Thermal Resistance Ratings

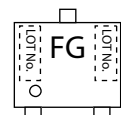
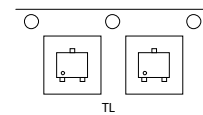
Parameter	Symbol	Value	Unit
Junction to Ambient When mounted on ceramic substrate (900mm ² × 0.8mm)	R _{θJA}	156.2	°C/W

Electrical Connection N-Channel



Packing Type : TL

Marking



Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

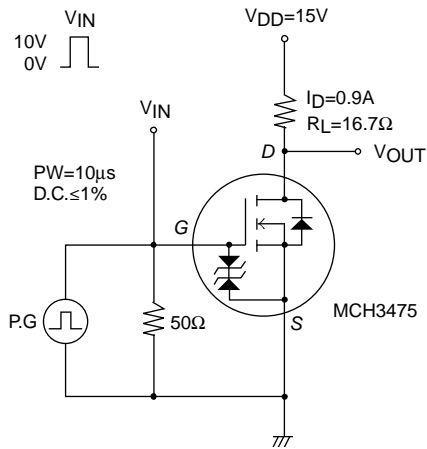
MCH3475

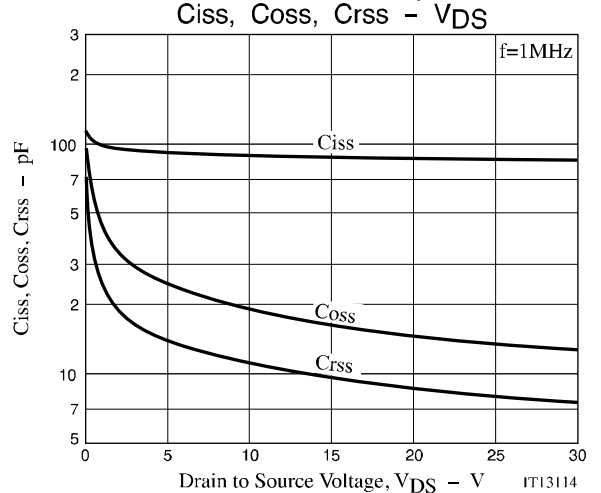
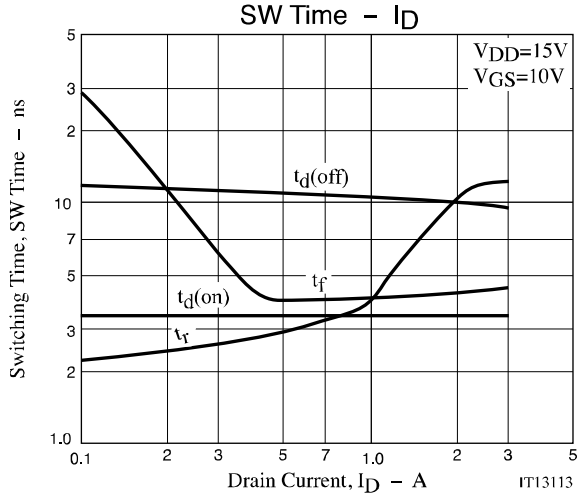
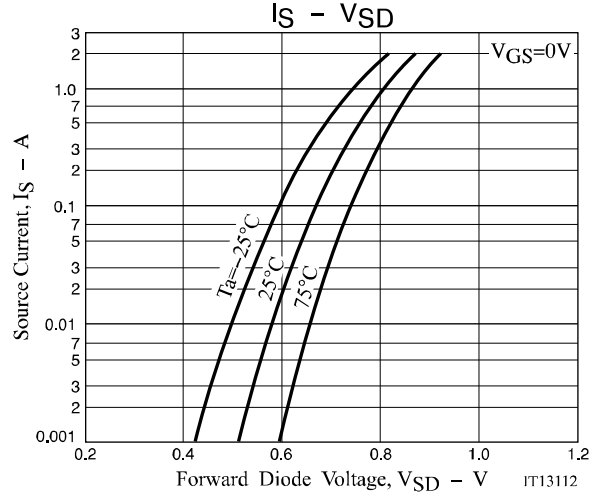
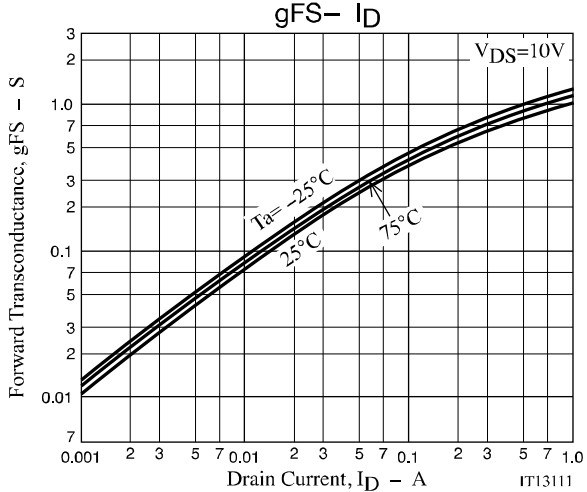
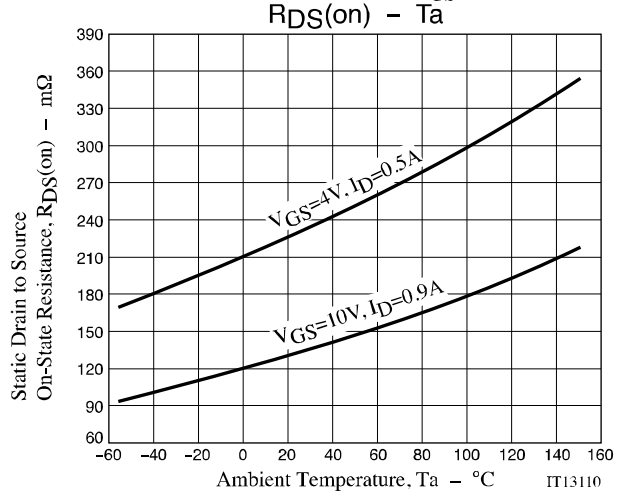
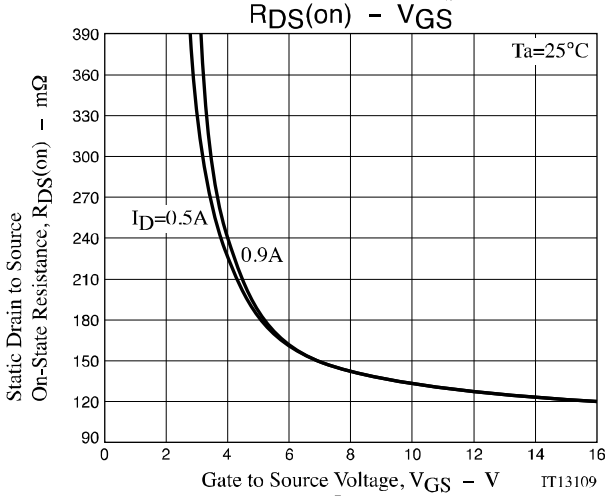
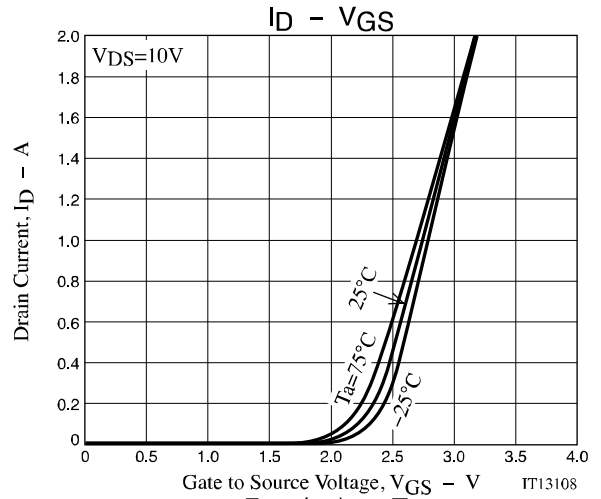
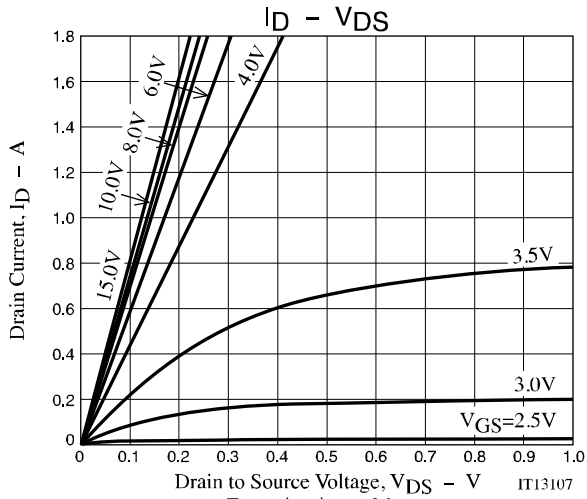
Electrical Characteristics at $T_a = 25^\circ\text{C}$

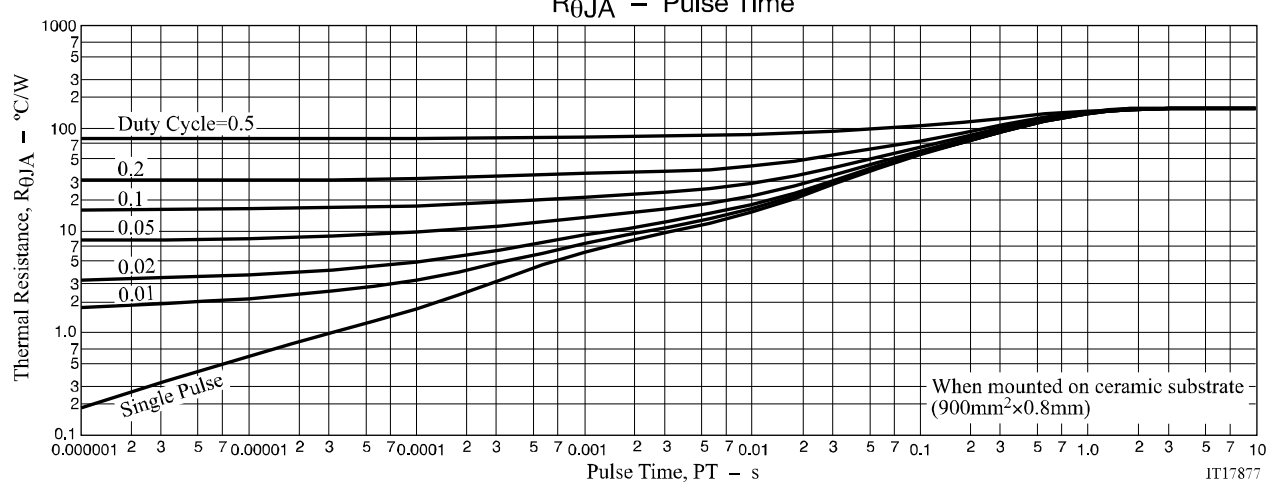
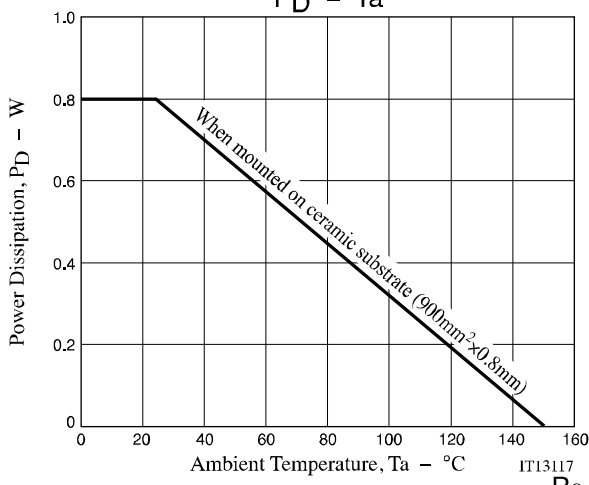
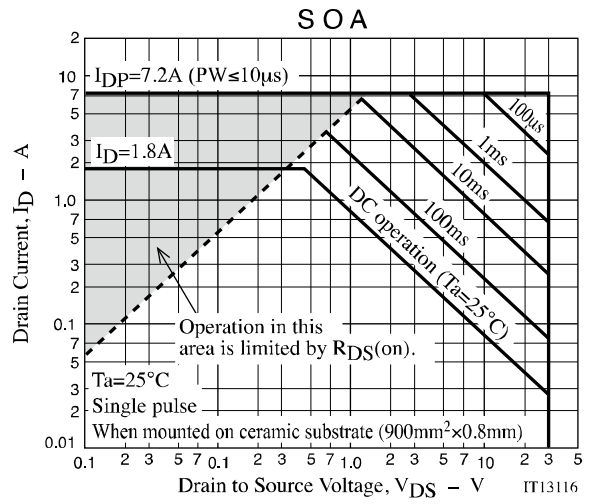
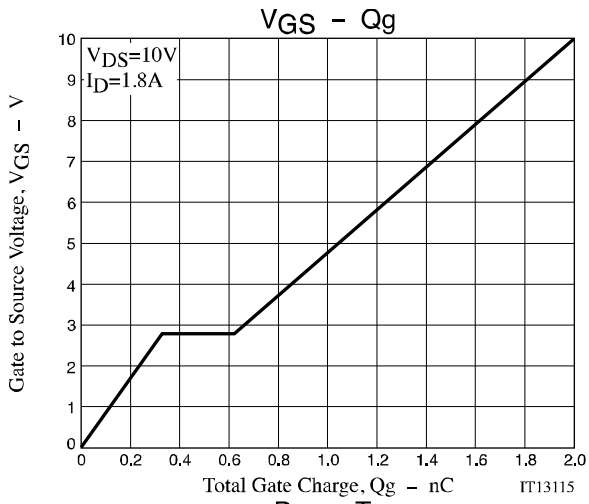
Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=1\text{mA}, V_{GS}=0\text{V}$	30			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=30\text{V}, V_{GS}=0\text{V}$			1	μA
Gate to Source Leakage Current	I_{GSS}	$V_{GS}=\pm 16\text{V}, V_{DS}=0\text{V}$			± 10	μA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=10\text{V}, I_D=1\text{mA}$	1.2		2.6	V
Forward Transconductance	g_{FS}	$V_{DS}=10\text{V}, I_D=0.9\text{A}$	0.66	1.1		S
Static Drain to Source On-State Resistance	$R_{DS(on)1}$	$I_D=0.9\text{A}, V_{GS}=10\text{V}$		135	180	$\text{m}\Omega$
	$R_{DS(on)2}$	$I_D=0.5\text{A}, V_{GS}=4\text{V}$		230	330	$\text{m}\Omega$
Input Capacitance	C_{iss}	$V_{DS}=10\text{V}, f=1\text{MHz}$		88		pF
Output Capacitance	C_{oss}			19		pF
Reverse Transfer Capacitance	C_{rss}			11		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit		3.4		ns
Rise Time	t_r			3.6		ns
Turn-OFF Delay Time	$t_{d(off)}$			10.5		ns
Fall Time	t_f			4.0		ns
Total Gate Charge	Q_g				2.0	
Gate to Source Charge	Q_{gs}	$V_{DS}=10\text{V}, V_{GS}=10\text{V}, I_D=1.8\text{A}$		0.33		nC
Gate to Drain "Miller" Charge	Q_{gd}			0.29		nC
Forward Diode Voltage	V_{SD}	$I_S=1.8\text{A}, V_{GS}=0\text{V}$		0.86	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Switching Time Test Circuit







MCH3475

Package Dimensions

MCH3475-TL-E / MCH3475-TL-W

MCPH3

CASE 419AQ

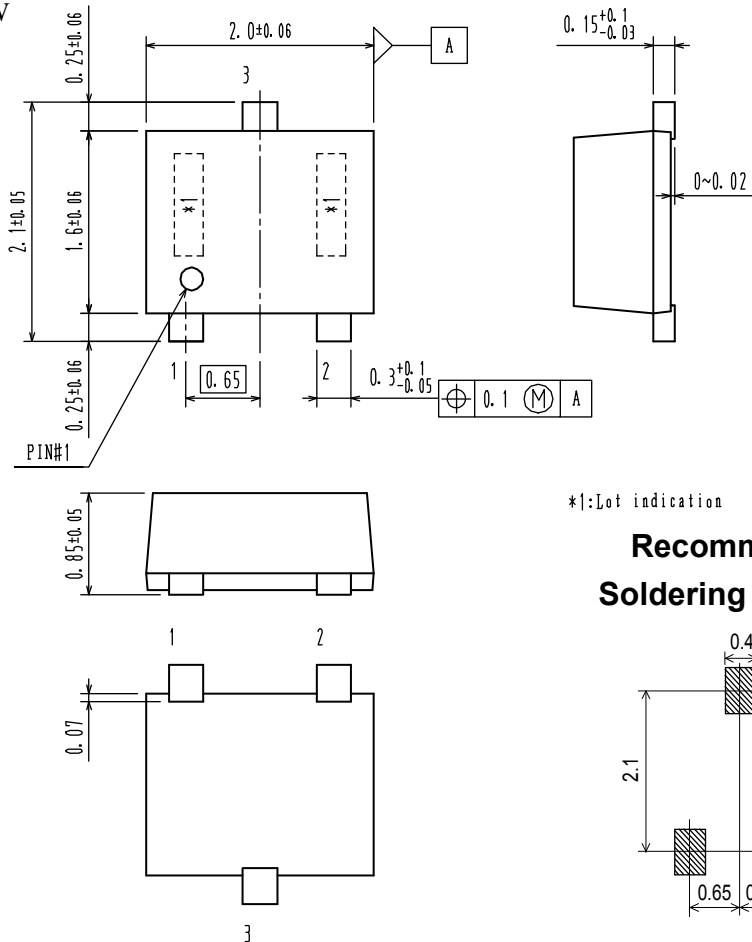
ISSUE O

Unit : mm

1 : Gate

2 : Source

3 : Drain



*]: Lot indication

Recommended Soldering Footprint

ORDERING INFORMATION

Device	Package	Shipping	Note
MCH3475-TL-E	MCPH3 SC-70FL, SOT-323	3,000 pcs. / Tape & Reel	Pb-Free
MCH3475-TL-W			Pb-Free and Halogen Free

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF

Note on usage : Since the MCH3475 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

ON Semiconductor and the ON logo are registered trademarks of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries. SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.